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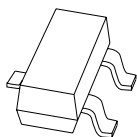
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Kind regards,

Team Nexperia



# BSS84

## P-channel enhancement mode vertical DMOS transistor

Rev. 06 — 16 December 2008

Product data sheet

## 1. Product profile

### 1.1 General description

P-channel enhancement mode vertical Diffusion Metal-Oxide Semiconductor (DMOS) transistor in a small Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number <sup>[1]</sup>	Package	
	NXP	JEDEC
BSS84	SOT23	TO-236AB
BSS84/DG		

[1] /DG: halogen-free

### 1.2 Features

- Low threshold voltage
- High-speed switching
- Direct interface to CMOS and Transistor-Transistor Logic (TTL)
- No secondary breakdown

### 1.3 Applications

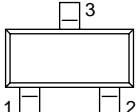
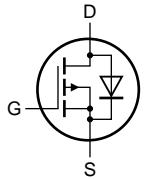
- Line current interrupter in telephone sets
- Relay, high-speed and line transformer drivers

### 1.4 Quick reference data

- $V_{DS} \leq -50\text{ V}$
- $I_D \leq -130\text{ mA}$
- $R_{DS(on)} \leq 10\ \Omega$
- $P_{tot} \leq 250\text{ mW}$

2. Pinning information

Table 2. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	 SOT23 (TO-236AB)	 001aaa025
2	S	source		
3	D	drain		

3. Ordering information

Table 3. Ordering information

Type number[1]	Package		
	Name	Description	Version
BSS84	TO-236AB	plastic surface-mounted package; 3 leads	SOT23
BSS84/DG			

[1] /DG: halogen-free

4. Marking

Table 4. Marking codes

Type number[1]	Marking code[2]
BSS84	13*
BSS84/DG	ZV*

[1] /DG: halogen-free

[2] \* = -: made in Hong Kong  
\* = p: made in Hong Kong  
\* = t: made in Malaysia  
\* = W: made in China

5. Limiting values

Table 5. Limiting values  
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage	$25\text{ }^{\circ}\text{C} \leq T_j \leq 150\text{ }^{\circ}\text{C}$	-	-50	V
$V_{GS}$	gate-source voltage		-	$\pm 20$	V
$I_D$	drain current	$T_{sp} = 25\text{ }^{\circ}\text{C}; V_{GS} = -10\text{ V};$ see Figure 1	-	-130	mA
		$T_{sp} = 100\text{ }^{\circ}\text{C};$ $V_{GS} = -10\text{ V}$	-	-75	mA
$I_{DM}$	peak drain current	$T_{sp} = 25\text{ }^{\circ}\text{C}; t_p \leq 10\text{ }\mu\text{s};$ see Figure 1	-	-520	mA
$P_{tot}$	total power dissipation	$T_{sp} = 25\text{ }^{\circ}\text{C};$ see Figure 2 [1]	-	250	mW
$T_{stg}$	storage temperature		-65	+150	$^{\circ}\text{C}$
$T_j$	junction temperature		-65	+150	$^{\circ}\text{C}$

[1] Device mounted on a Printed-Circuit Board (PCB).

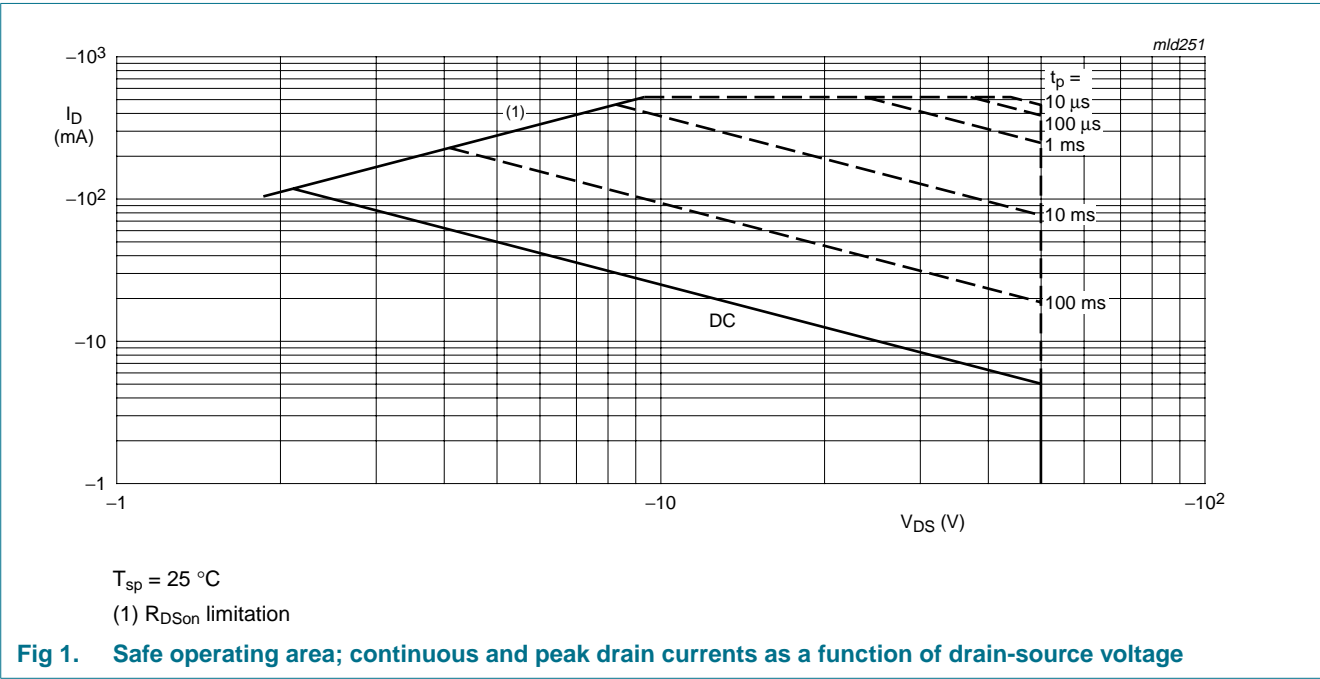


Fig 1. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

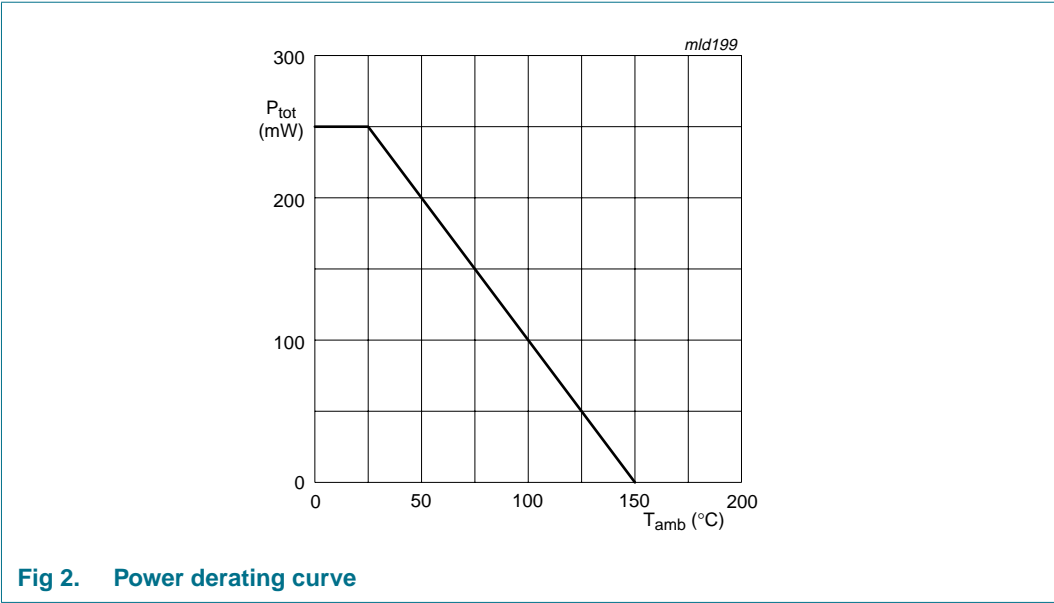


Fig 2. Power derating curve

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	see <a href="#">Figure 3</a>	[1]	-	500	K/W

[1] Mounted on a PCB, vertical in still air.

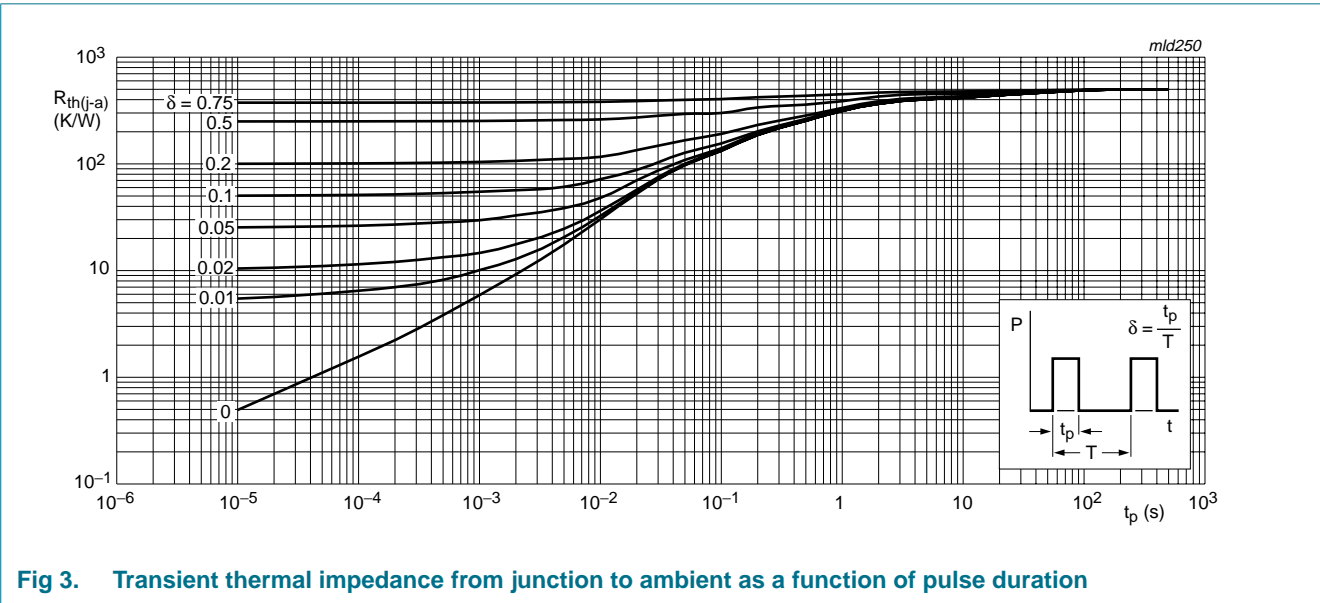


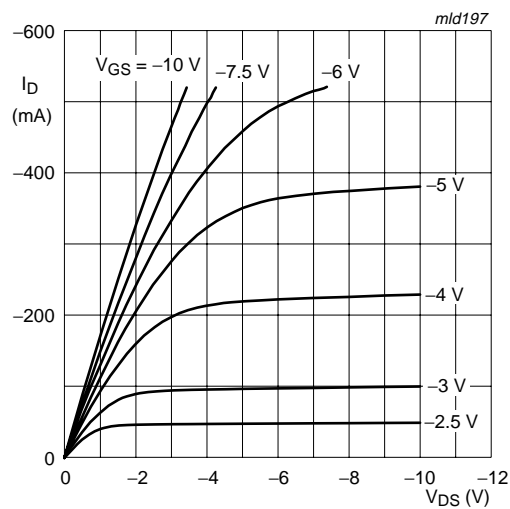
Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration

## 7. Characteristics

**Table 7. Characteristics**

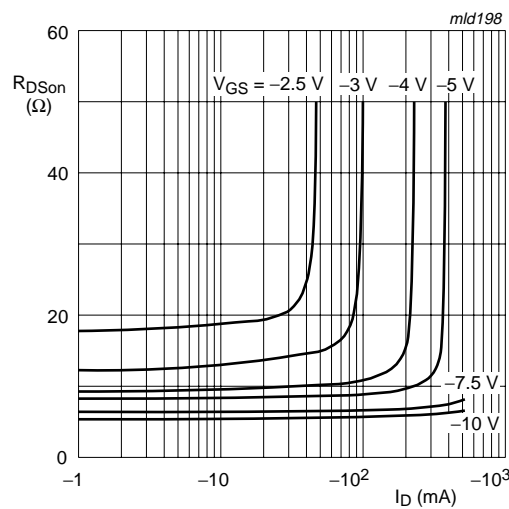
$T_j = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = -10\text{ }\mu\text{A}$ ; $V_{GS} = 0\text{ V}$	-50	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = -1\text{ mA}$ ; $V_{DS} = V_{GS}$ ; see <a href="#">Figure 8</a>				
		$T_j = 25\text{ }^{\circ}\text{C}$	-0.8	-	-2	V
		$T_j = -55\text{ }^{\circ}\text{C}$	-	-	-1.8	V
$I_{DSS}$	drain leakage current	$V_{DS} = -40\text{ V}$ ; $V_{GS} = 0\text{ V}$				
		$T_j = 25\text{ }^{\circ}\text{C}$	-	-	-100	nA
		$V_{DS} = -50\text{ V}$ ; $V_{GS} = 0\text{ V}$				
		$T_j = 25\text{ }^{\circ}\text{C}$	-	-	-10	$\mu\text{A}$
$I_{GSS}$	gate leakage current	$V_{GS} = +20\text{ V}$ ; $V_{DS} = 0\text{ V}$	-	-	100	nA
		$V_{GS} = -20\text{ V}$ ; $V_{DS} = 0\text{ V}$	-	-	100	nA
		$T_j = 125\text{ }^{\circ}\text{C}$	-	-	-60	$\mu\text{A}$
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = -10\text{ V}$ ; $I_D = -130\text{ mA}$ ; see <a href="#">Figure 5</a> and <a href="#">7</a>	-	6	10	$\Omega$
<b>Dynamic characteristics</b>						
$ Y_{fs} $	transfer admittance	$V_{DS} = -25\text{ V}$ ; $I_D = -130\text{ mA}$	50	-	-	mS
$C_{iss}$	input capacitance	$V_{GS} = 0\text{ V}$ ; $V_{DS} = -25\text{ V}$ ; $f = 1\text{ MHz}$ ; see <a href="#">Figure 9</a>	-	25	45	pF
$C_{oss}$	output capacitance		-	15	25	pF
$C_{rss}$	reverse transfer capacitance		-	3.5	12	pF
$t_{on}$	turn-on time	$V_{DS} = -40\text{ V}$ ; $V_{GS} = 0\text{ V}$ to $-10\text{ V}$ ; $I_D = -200\text{ mA}$ ; see <a href="#">Figure 10</a> and <a href="#">11</a>	-	3	-	ns
$t_{off}$	turn-off time	$V_{DS} = -40\text{ V}$ ; $V_{GS} = -10\text{ V}$ to $0\text{ V}$ ; $I_D = -200\text{ mA}$ ; see <a href="#">Figure 10</a> and <a href="#">11</a>	-	7	-	ns



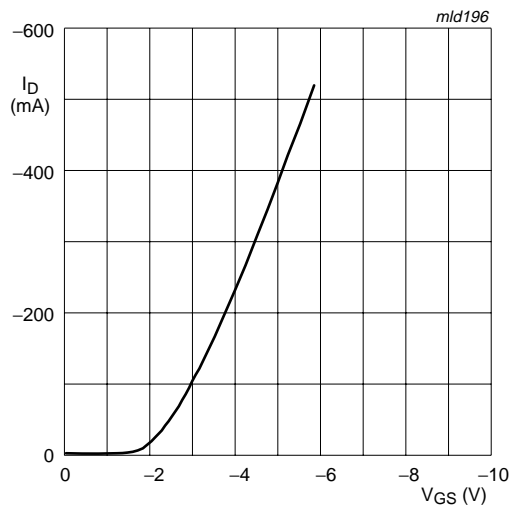
$T_j = 25\text{ }^{\circ}\text{C}$

Fig 4. Output characteristics: drain current as a function of drain-source voltage; typical values



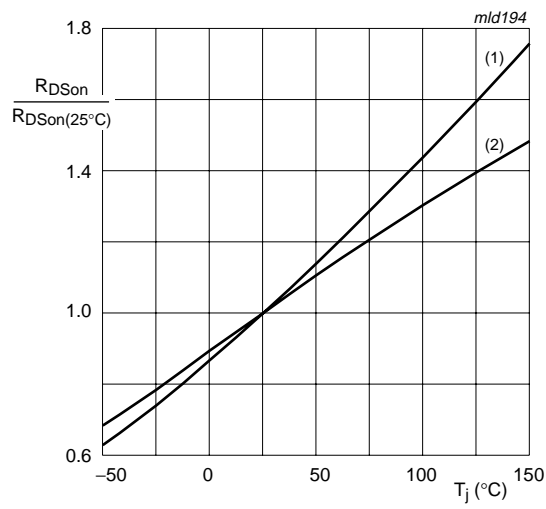
$T_j = 25\text{ }^{\circ}\text{C}$

Fig 5. Drain-source on-state resistance as a function of drain current; typical values



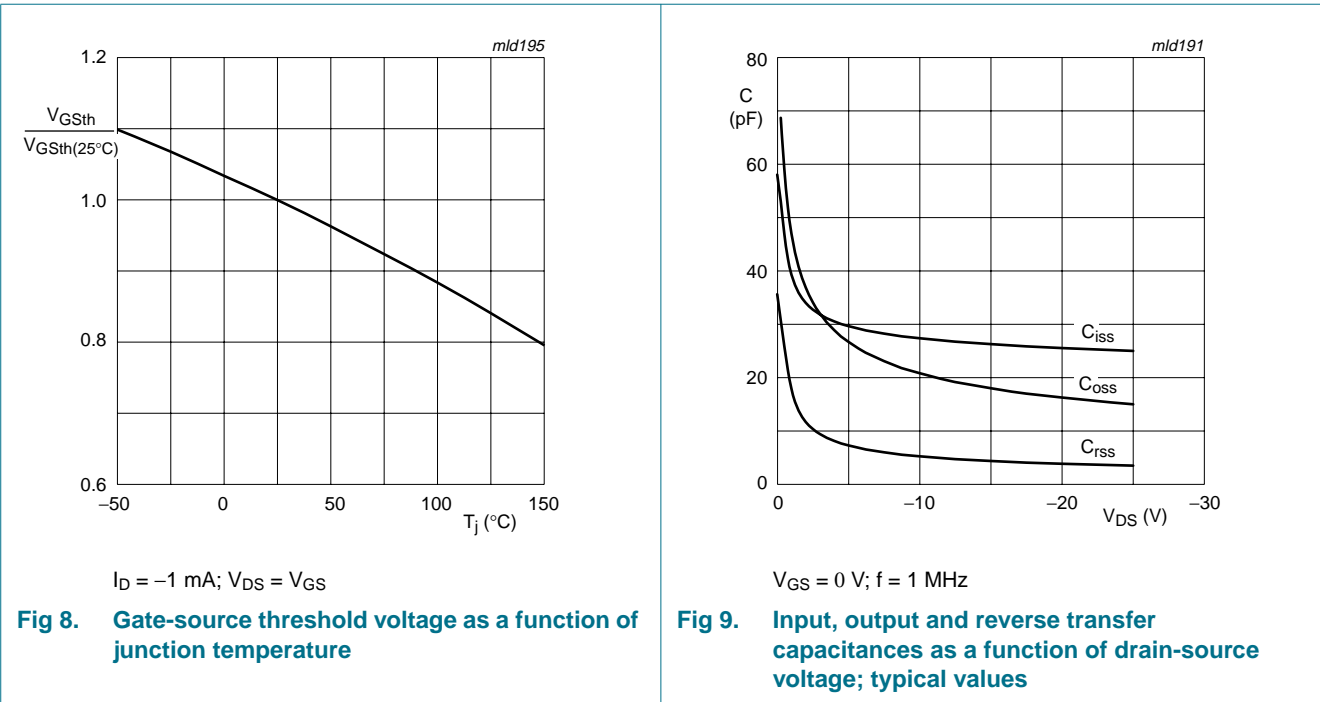
$T_j = 25\text{ }^{\circ}\text{C}; V_{DS} = -10\text{ V}$

Fig 6. Transfer characteristics: drain current as a function of gate-source voltage; typical values

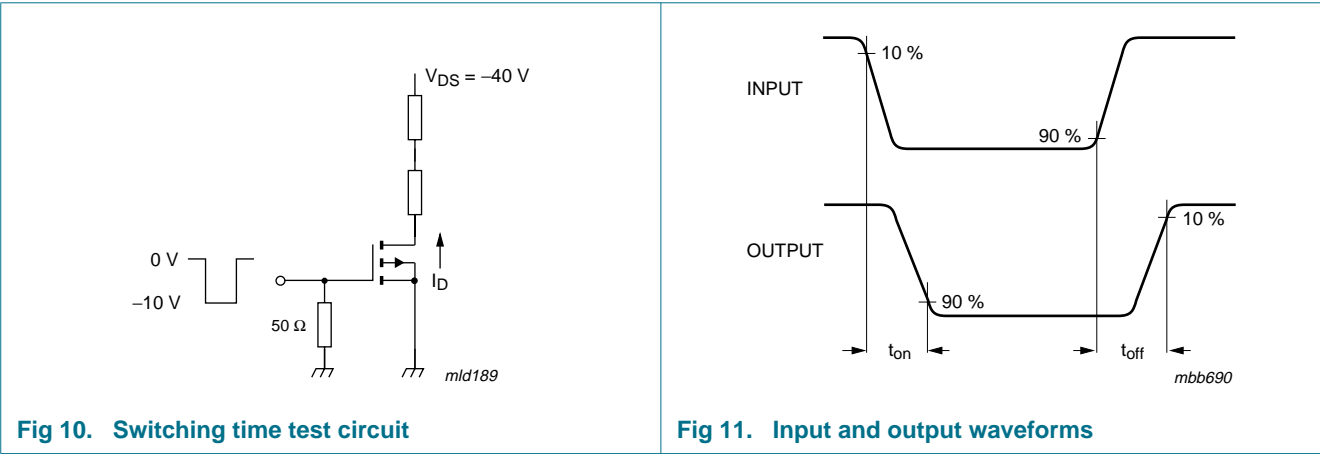


(1)  $I_D = -130\text{ mA}; V_{GS} = -10\text{ V}$   
(2)  $I_D = -20\text{ mA}; V_{GS} = -2.4\text{ V}$

Fig 7. Normalized drain-source on-state resistance factor as a function of junction temperature



8. Test information





9. Package outline

Plastic surface-mounted package; 3 leads

SOT23

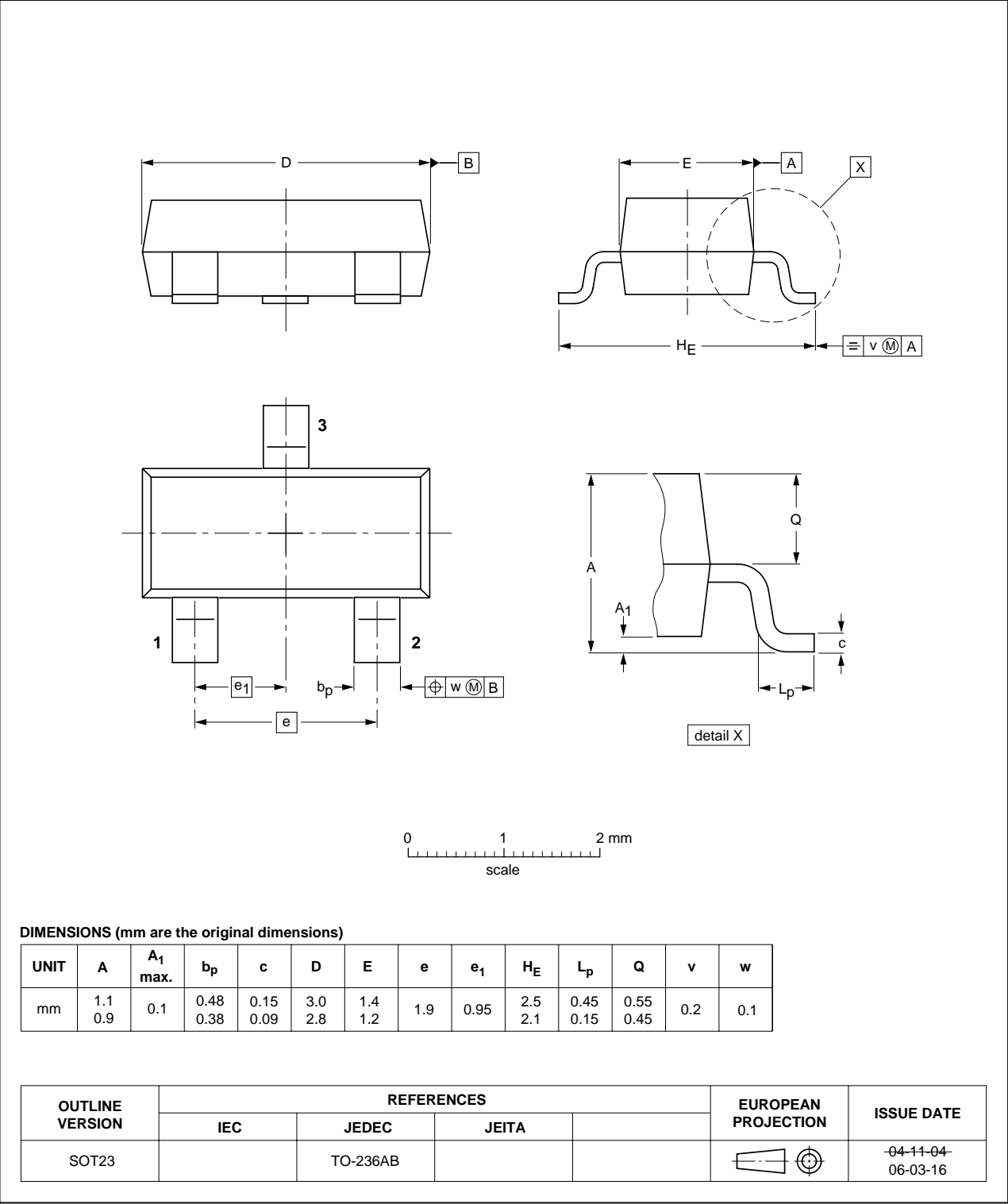


Fig 12. Package outline SOT23 (TO-236AB)

## 10. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BSS84_6	20081216	Product data sheet	-	BSS84_5
Modifications:	• <a href="#">Table 5 “Limiting values”</a> : $P_{\text{tot}}$ figure reference updated			
BSS84_5	20081209	Product data sheet	-	BSS84_4
BSS84_4	20070717	Product data sheet	-	BSS84_3
BSS84_3	20030804	Product specification	-	BSS84_2
BSS84_2	19970618	Product specification	-	BSS84_1
BSS84_1	19950407	Product specification	-	-

## 11. Legal information

### 11.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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